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#### **DESIGNER'S DATA SHEET**

### Part Number / Ordering Information <sup>1</sup>

SFT10015

Screening <sup>2/</sup>
= Not Screened

TX = TX Level
TXV = TXV Level

S = S Level

Package

/3 = TO-3

## SFT10015

# 50 AMP NPN DARLINGTON TRANSISTOR 400 VOLTS

#### Features:

- BV<sub>CEO</sub> 400 Volts
- Low Saturation Voltage
- 200°C Operating Temperature
- Hermetically Sealed, Isolated Package
- TX, TXV, S-Level Screening Available. Consult Factory.

#### **Application Notes:**

SFT10015 Darlington Transistor is a direct replacement of Motorola MJ10015. It is designed for high voltage, high speed, power switching in inductive circuits where fall time is critical. It is particularly suited for line operated switchmode applications such as:

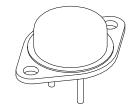
- Switching Regulators
- Inverters
- Solenoid and Relay Drives
- Motor Controls
- Deflection Circuits

Maximum Ratings		Symbol	Value	Units
Collector – Emitter Voltage		V <sub>CEO</sub>	400	Volts
Collector – Emitter Voltage		$V_{\sf CEV}$	600	Volts
Emitter – Base Voltage		$V_{EB}$	8	Volts
Collector Current	Continuous Peak	I <sub>C</sub> I <sub>CM</sub>	50 75	Amps
Base Current	Continuous Peak	I <sub>B</sub> I <sub>BM</sub>	10 15	Amps
Total Power Dissipation  Derate above 50°C	@ T <sub>C</sub> = 25°C @ T <sub>C</sub> = 100°C	P <sub>D</sub>	250 143 1.43	Watts Watts W/°C
Operating & Storage Temperature		T <sub>J</sub> & T <sub>STG</sub>	-65 to +200	°C
Maximum Thermal Resistance (Junction to Case)		R <sub>eJC</sub>	0.7	°C/W

#### **NOTES:**

- $\underline{1}/$  For ordering information, price, operating curves, and availability contact factory.
- 2/ Screening based on MIL-PRF-19500. Screening flows available on request.

TO-3(/3)



**NOTE:** All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: TR0126B

DOC



SFT10015

Electrical Characteristics, T <sub>c</sub> = 25 °C		Symbol		Min	Тур	Max	Units	
Collector – Emitter Sustaining Voltage $(I_C = 100 \text{ mA}, I_B = 0, V_{CLAMP} = 400 \text{ V})$		$V_{CEO(sus)}$		400		_	Volts	
Collector Cutoff Current $(V_{CEV} = 600 \text{ V}, V_{BE(off)} = 1.5 \text{V})$		I <sub>CEV</sub>				0.25	mA	
Emitter Cutoff Current $(V_{EB} = 2V, I_C = 0)$		I <sub>EBO</sub>			160	350	mA	
DC Current Gain* $I_{C} = 10 \text{ A}$ $(V_{CE} = 5V)$ $I_{C} = 20 \text{ A}$ $I_{C} = 40 \text{ A}$		H <sub>FE</sub>		 25 10	185 125 50			
Collector-Emitter	Saturation Voltage*	$I_C = 20 \text{ A}, I_B = 1 \text{ A}$ $I_C = 50 \text{ A}, I_B = 10 \text{ A}$	V <sub>CE</sub>	(SAT)		1.3 2.1	2.2 5.0	Volts
Base-Emitter Saturation Voltage* $I_C = 20A$ , $I_B = 1A$ , $T_C = 25^{\circ}C$		V <sub>BE (SAT)</sub>			2.05	2.75	Volts	
<b>Diode Forward Voltage</b> $I_F = 20 \text{ A}$		$V_{F}$			2.0	5.0	Volts	
5V, 50A <b>Safe Operating Area, DC</b> (1 sec) 20V, 8.75A 100V, 0.3A		SOA <sub>1</sub> SOA <sub>2</sub> SOA <sub>3</sub>				_		
Output Capacitance $(V_{CB} = 10V, I_E = 0A, f = 1MHz)$		C <sub>ob</sub>			250	750	рF	
Delay Time Rise Time	Switching Times,		t <sub>(on)</sub>	t <sub>d</sub> t <sub>r</sub>		0.15 1.0	0.3 1.2	μs μs
Storage Time Fall Time	$V_{CC}$ = 250 V, $I_{C}$ = 20 A, $I_{B1}$ = 1 A, $V_{BE (off)}$ = 5 V, tp = 25 $\mu$ s, Duty Cycle ≤ 2%		t <sub>(off)</sub>	t <sub>s</sub>		2.2 0.95	2.5 1.2	μs μs
Storage Time	Switching Times, Inductive Load, Clamped $I_C = 20 \text{ A(pk)}, V_{CLAMP} = 250 \text{ V},$ $I_{B1} = 1 \text{ A}, V_{BE (off)} = 5 \text{ V}, T_C = 25^{\circ}\text{C}$		t <sub>sv</sub>			12		μs
Crossover Time			t <sub>c</sub>			7.3		μs

#### NOTES:

<sup>\*</sup> Pulse Test: Pulse Width = 300µsec, Duty Cycle = 2%

